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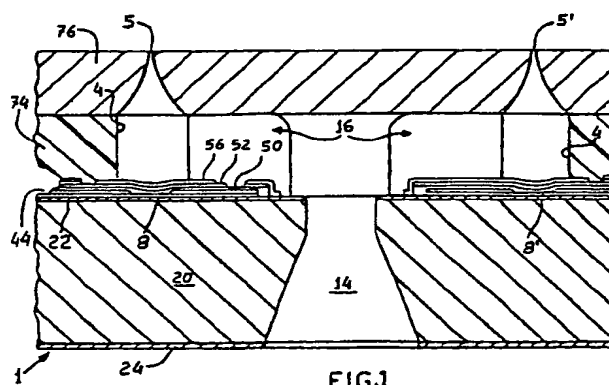
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(54) **Process for the manufacture of thermal ink jet printing heads and heads obtained in this way.**

(57) Each thermal ink jet printing head (1) comprises a multi-layer plate in which layers of metals and of insulating materials are successively deposited under vacuum on a silicon base plate (20). The ink is contained in expulsion chambers (4) formed by a photolithographic process in a layer of photosensitive resin (74) and is expelled by the effect of rapid heating of resistive elements (8) contained within the expulsion chambers through nozzles (5) disposed in two rows side by side and produced in a metal lamina stuck to the resin layer. The expulsion chambers communicate with a main reservoir through a common ink feed duct (14) in the form of a slot or groove disposed between the two rows of nozzles and cut through the silicon plate (20) partly by an etching process and partly by a sandblasting process or with a special type of laser (excimer).



**EP 0 401 996 A2**

## PROCESS FOR THE MANUFACTURE OF THERMAL INK JET PRINTING HEADS AND HEADS OBTAINED IN THIS WAY

The present invention relates to a process for the manufacture of a thermal ink jet printing head and more particularly to the production of a duct for the ink for a thermal ink jet printing head of the type in which the nozzles, the ink expulsion chambers and the heating elements with the corresponding electric conductors are contained in a multi-layer plate formed by superposed layers of metals and insulating materials fixed on a silicon support.

There are known in the art thermal ink jet printing heads in which the ink feed duct is obtained by cutting a slit extending through the multi-layer plate for its entire thickness by means of a jet of sand formed by particles of very hard materials, for example alumina, with sizes of the order of 10-25  $\mu\text{m}$ .

Since such a process is necessarily applied to the complete multi-layer plate, the sand jet must cut into a relatively considerable thickness of the order of 0.5-0.7 mm. In such case, the terminal opening of the slit turns out of very inaccurate geometrical shape, causing a large number of rejects, which make the process more costly.

Also known is the cutting of the common duct for the ink in a multi-layer plate for an ink jet head by means of a laser beam of conventional type, for example YAG, CO<sub>2</sub>. Since the conventional types of laser beams operate by thermal effect, they cause the melting of a surface layer of the sides of the cut.

When this molten layer solidifies, it becomes very fragile and, by reason of the thermal stresses due to its cooling, is subject to extensive cracking. In consequence, infiltration of ink will occur through these cracks during the working of the head, with a consequent reduction in the life of the head.

Therefore, the present invention aims to provide a process for cutting the ink duct in a multi-layer plate for a thermal ink jet printing head which is free from the above-mentioned drawbacks.

Another aim of the invention is to produce cuts for the ink duct of geometrical form in multi-layer plates for thermal ink jet printing heads, which are very accurate, and have clean edges, over a greatly reduced production time.

Accordingly, the invention provides a process, which is characterised in the manner defined in the main claim.

An embodiment of the invention will now be described by way of example only, and, with reference to the accompanying drawings in which:

Fig. 1 represents diagrammatically a cross section of a multi-layer plate obtained according to the invention;

Figs. 2 - 8 represent successive stages of working of the plate of Fig. 1.

Referring to Fig. 1, a multi-layer plate 1 comprises a plurality of metal layers and electrically insulating in which each layer is constructed by processes of vacuum deposition and electroforming which are known in the art.

The ink is contained in chambers 4 produced in one of the layers of the plate 1 and is expelled through nozzles 5 and 5' disposed in two parallel rows by the effect of the expansion of a vapour bubble generated by the rapid heating of heating elements 8 and 8' contained in the chambers 4.

The plate 1 is used on a thermal ink jet dot printing head mounted immovably directly on a main ink reservoir not shown in the drawings.

Each row of nozzles may contain a variable number of nozzles which is determined on the basis of the printing requirements, such as, for example, the level of definition of the characters.

The main reservoir communicates with the chambers 4 through a common duct 14 (Fig. 1) produced in the thickness of the plate 1 and through a plurality of feed passages 16 connecting each chamber 4 with the common duct 14.

The process for cutting the common duct 14 through the thickness of the silicon support 20 is as

A silicon support plate 20 of a thickness in the range between 400  $\mu\text{m}$  and 700  $\mu\text{m}$  is passivated on both faces with a layer 22 and 24, respectively, of silicon dioxide with a thickness, for example, of 1.5  $\mu\text{m}$ , these layers performing the function of thermal and electrical insulation. The layers 22 and 24 are covered with two protective layers 26 and 28 of a photosensitive substance. Such photosensitive substances are normally epoxy and/or acrylic resins polymerizable by the effect of light radiation. After being exposed and developed, the protective layer 28 is removed by the known photolithographic technique to form an aperture 30 (Fig. 2) of rectangular form extending lengthwise in the direction parallel to the crystallographic orientation  $\langle 110 \rangle$  of the silicon support 20. Consequently, the rows of heating elements 8 and 8' will be aligned parallel to this direction. The aperture 30 leaves free a zone 32 (Fig. 2) of the layer 24 of silicon dioxide. The zone 32 is thereafter removed chemically with a selective, hydrofluoric acid (HF) based solution to uncover a portion 34 of the support 20 (Fig. 3). After removing the protective layers 26 and 28, the support 20 is immersed in an attack bath for etching the surface 34.

Since the support 20 is constituted by cry-

stalline silicon having a standard crystallographic orientation of  $\langle 100 \rangle$ , the etching action of the anisotropic attack solution develops predominantly in accordance with the orientation of  $\langle 100 \rangle$  and much less in accordance with the associated orientation of  $\langle 111 \rangle$ . With respect to the silicon support 20, the orientation  $\langle 100 \rangle$  corresponds to a direction X (Fig. 2) perpendicular to the outer faces of the support 20, the orientation  $\langle 100 \rangle$  represents a direction Y perpendicular to X and the orientation  $\langle 111 \rangle$  represents a direction Z perpendicular to Y and forming with the direction X a characteristic angle  $\alpha$  dependent on the form of the crystal lattice of the material of the support 20. Therefore, the groove 35 (Fig. 4) which is obtained after the etching process has in cross-section the form of a truncated pyramid (Fig. 4) having as its greater base the surface 34 (Fig. 3) parallel to the outer faces of the support 20 and as its smaller or truncation base a surface 36 (Fig. 4) parallel to the surface 34, the width L of which depends on the depth  $H_1$  reached by the etching and on the width  $L_1$  of the zone 34. The length of the groove 35 in the direction perpendicular to the drawing depends on the number of nozzles 5 employed in each row. The lateral surfaces 38 and 40 have a characteristic inclination  $\alpha$  with respect to the greater base 34 of about  $54^\circ$ , corresponding to the angle between the crystallographic orientations  $\langle 100 \rangle$  and  $\langle 111 \rangle$  of the silicon support 20. The widths L,  $L_1$  are linked to the depth  $H_1$  of the groove 35 and to the inclination  $\alpha$  by the equation:

$$L_1 = L - 2H_1 \cot \alpha \quad (1)$$

The solutions most usual for anisotropic etching of silicon are the following:

A. Ethylenediamine : 750 ml

Pyrocatechol : 120 gr

Deionized water : 100 ml.

This solution, operating at a temperature of  $115^\circ\text{C}$ , develops an attack gradient in accordance with the orientation  $\langle 100 \rangle$  :  $G_{100} = 0.75 \mu\text{m}/\text{min}$  and a ratio

$$G_{100}/G_{111} = 35:1,$$

where  $G_{111}$  is the anisotropic attack gradient in accordance with the orientation  $\langle 111 \rangle$ .

B. Ethylenediamine : 750 ml

Pyrocatechol : 120 gr

Deionized water : 240 ml

This solution, operating at a temperature of  $115^\circ\text{C}$ , gives:  $G_{100} = 1.25 \mu\text{m}/\text{min}$ ;

$$G_{100}/G_{111} = 35:1.$$

C. Potassium hydroxide: 250 gr

Isopropyl alcohol : 200 ml

(isopropanol)

Deionized water : 800 ml

This solution, operating at a temperature of  $80^\circ\text{C}$ , gives  $G_{100} = 1 \mu\text{m}/\text{min}$ ;

$$G_{100}/G_{111} = 400:1.$$

D. Hydrazine : 600 ml

Deionized water: 400 ml

This solution, operating at a temperature of  $100^\circ\text{C}$ , gives  $G_{100} = 1.8 \mu\text{m}/\text{min}$ .

The operation of etching of the groove 35 (Fig. 4) is continued for an attack time T depending on the attack gradient  $G_{100}$  and until the end surface 36 reaches a depth  $H_1$  comprised between 60% and 90% of the thickness H of the support 20.

By way of example, with a support 20 of a thickness  $H = 600 \mu\text{m}$ , the depth  $H_1$  of the groove 35 to be etched is about  $400 \mu\text{m}$ . Having fixed a width L of the surface 36 of about  $350 \mu\text{m}$ , there is obtained from the equation 1) the width  $L_1$  of the zone 34 (Fig. 3) from which the operation of etching begins, that is  $L_1 = 926 \mu\text{m}$ .

Using, for example, the solution A, the attack time T lasts 8 hours and 55 minutes. After etching the groove 35 for a depth  $H_1$ , metal layers are successively deposited under vacuum on the layer 22 of silicon dioxide by known deposition techniques to form the heating elements 8, 8' and the corresponding electric conductors, for example as described in Italian Patent Application No. 67044 A/89, dated 26.1.89, in the name of the Applicant.

More particularly, the silicon dioxide layer 22 is covered with a layer 44 (Fig. 5) between 500 and 2000 Å thick of an electrically resistive metal, for example a 50/50 tantalum-aluminium alloy. The layer 44 is then etched by a known process of dry etching under vacuum to form two pluralities of independent resistive elements 8 and 8' for heating the ink.

The Ta-Al elements 8, 8' are covered with a layer 46 of aluminium with a thickness comprised between 2000 and 10,000 Å. the layer 46 is then etched by a process similar to the foregoing to obtain electric conductors 47 for supplying the heating elements 8 and 8'. On the aluminium layer 46 there are then deposited two layers 50 and 52 of electrically insulating, but thermally conductive, materials. The layer 50 in contact with the alumin-

ium conductors 47 is constituted by silicon nitride, while the overlying layer 52 is constituted by silicon carbide. In total, the two layers 50 and 52 have a thickness comprised between 2000 and 20,000 Å.

A layer 56 of tantalum of a thickness between 1000 Å and 10,000 Å is thereafter deposited by known techniques on the layer 52. The layer 56 is then etched under vacuum to obtain separate and parallel strips superposed on the conductors 47.

The layer 56 has a dual function of protection of the ink of the subjacent resistive and insulating layers and of electrical connection between the conductors 47 and connecting terminals (not shown) towards the outside.

The layers 44, 46, 50, 52 and 56 are interrupted in an intermediate zone 60 (Fig. 5) between the two rows of the heating elements 8 and 8', leaving free a part 62 of the layer 22. More particularly, the tantalum layer 56 also covers the edges 58 of the subjacent layers to protect them from possible infiltrations of acids employed in the etching treatments and from the ink during the operation of the head.

The breaking through of the residual wall 36', which has a thickness of  $H_2 = H - H_1$ , is thereafter carried out by a sandblasting operation.

To this end, a jet of sand formed predominantly of alumina particles of an average size of about 20 µm is directed against the end surface 36 in a direction perpendicular to the surface itself.

The sandblasting operation is interrupted when an opening 63 (Fig. 6) defined by two plane and parallel walls 64 and 66 has been obtained in the surface 62. The walls 64 and 66 are connected at one end to the lateral surfaces 38 and 40, respectively, of the groove 35 and intersect at the other end (at the top in Fig. 6) the surface 62. The walls 64 and 66 and the surface 62 therefore define a parallelepipedal chamber 69 having the truncation base 36 in common with the pyramidal chamber. After completing the cutting of the common duct 14 (Fig. 1), there is deposited on the tantalum layer 56, as described in the above-mentioned Patent Application, a layer 74 of photosensitive material, for example Vacrei (Registered Trade Mark), in which the chambers 4 and the feed passages 16 are obtained by a photolithographic process. Finally, a sheet 76 of gold-plated nickel bearing the nozzles 5 and 5' is hot-soldered to the layer 74.

It remains understood that the process of construction of the thermal ink jet head may undergo variations of modifications and that the thermal head so constructed may be modified in form and dimensions without, however, departing from the scope of the invention.

For example, the sandblasting process previously described may be substituted alternatively

by a process of cutting by means of a laser beam of the "excimer" (excited dimer) type.

This type of laser is particularly suitable for machining solid materials, such as, for example, silicon and silicon dioxide, inasmuch as the excimer laser operates in a cold state without overheating the parts machined and without leaving traces of melting on the surfaces struck by the laser beam.

The excimer laser beam generates a very small portion of heat, inasmuch as the energy of the laser beam acts on the molecular bonds of the struck material, overcoming the forces of cohesion. The removal of material therefore takes place by ablation of particles, rather than through thermal phenomena such as melting, vaporization or sublimation.

This mechanism of ablation of particles confers on the machined parts a degree of precision much higher than that obtainable with other conventional types of laser beams, such as a CO<sub>2</sub> or YAG laser beam.

In order to construct plates for thermal ink jet heads industrially in large numbers by the process described hereinbefore, a disc 80 (Fig. 7) of silicon of circular form with a diameter of about 100 mm and about 0.5 mm thick is normally used as the supporting base 20. A cutaway portion 81 at the edge of the disc 80 commonly indicates the crystallographic orientation <100> of the disc 80. On this disc there are produced at the same time numerous identical configurations 82 of plates which, when construction has taken place, are separated by means of crossed cuts in the support disc along intermediate lines 83. Fig. 8 shows on an enlarged scale a part 84 of the disc 80 comprising a slot 63 seen from the direction of the surface 62 of Fig. 6. A panel 85 in chain-dotted lines represents the area occupied on the surface of the disc 80 by the layers 50, 52, 56 (Fig. 5) of each individual plate. In this case, the process hereinbefore described for etching slots for feeding the ink in each individual plate finds valid application, enabling a plurality of slots of the type of the groove 35 (Fig. 4) to be obtained simultaneously with a single etching operation, with a considerable reduction in the working times and costs.

## Claims

1. A process for the manufacture of an ink duct in a thermal ink jet printing head of the type in which ink expulsion chambers (4), heating (8, 8') for heating the ink, and elements are produced in a plurality of superposed layers fixed on a support element (20) defined by two opposed and parallel plane surfaces, the duct

(14) being in communication with the chambers and being formed through the thickness of the support element, the process comprising the steps of:

a) defining an area of predetermined shape on a first of the said surfaces;

b) treating the said support element with an etching composition for a predetermined time etch within the said area a recess extending in at least one preferred direction and having an end wall at a pre-determined depth;

c) constructing the said plurality of superposed layers on a second of said surfaces around the said recess; and

d) removing material of the said support element within the said recess and in the said preferred direction between the said end wall and the said second surface.

2. A process as claimed in Claim 1, characterised in that the said support element comprises a plate of crystalline silicon cut in accordance with a crystallographic orientation of  $\langle 100 \rangle$ .

3. A process as claimed in claim 2, characterised in that the said preferred direction corresponds to the crystallographic orientation of  $\langle 100 \rangle$  of the said support element and is perpendicular to the said surfaces of the said element.

4. A process as in any one of the preceding claims, characterised in that the step d) comprises the application of a sandblasting jet to the end of the said recess in the said preferred direction.

5. Process as claimed in any one of claims 1 to 3, characterised in that the step d) comprises the application of an excimer laser beam orientated in the said preferred direction to the end of the said recess.

6. Process as claimed in any one of the preceding claims, characterised in that the said etching composition comprises a mixture of ethylenediamine and pyrocatechol dissolved in deionized water.

7. Process as claimed in any one of claims 1 to 5, characterised in that the said etching composition comprises a mixture of potassium hydroxide and isopropanol dissolved in deionized water.

8. Process as claimed in any one of claims 1 to 5, characterised in that the said etching composition comprises a solution of hydrazine in deionized water.

9. Process as claimed in any one of the preceding claims, characterised in that the said etching composition has a maximum characteristic attack gradient in the direction  $\langle 100 \rangle$ .

10. Process as claimed in claim 9, characterised in that the said attack time depends on the said characteristic gradient and on the pre-established depth.

11. Process as claimed in any one of the

preceding claims, characterised in that the said pre-established depth is comprised between 60% and 90% of the thickness of the said support element.

12. Process as claimed in any one of the preceding claims, characterised in that the step a) comprises the following steps:

e) applying protective layers of materials resistant to chemical agents to both the said surfaces of the said support element; and

f) removing a part of the said protective layers on the said first surface to define the said area of predetermined shape.

13. Process as claimed in claim 12, characterised in that the said protective layers comprise a first layer of silicon dioxide superposed on both the said opposed surfaces and a layer of photosensitive synthetic material resistant to chemical agents which is superposed on the said first layer.

14. Process as claimed in claim 13, characterised in that the said photosensitive synthetic material comprises polymerizable epoxy and/or acrylic resins.

15. Process as claimed in claim 13 or 14, characterised in that the said step f) moreover comprises the following steps:

g) exposing an area of predetermined shape of the said photosensitive layer on the said first surface;

h) developing the said exposed layer and completely removing the said first layer in the portion subjacent the said area by means of a selective etching treatment.

16. Thermal ink jet printing head for a non-impact printer of the type in which ink contained in expulsion chambers is expelled through a plurality of nozzles arranged in two spaced, parallel rows by means of the selective heating of heating elements contained in each chamber, and in which the nozzles, the expulsion chambers, the heating elements and the corresponding electric supply conductors are formed in a plurality of layers of metal and insulating materials superposed on each other and fixed on a silicon support plate defined by two plane, parallel surfaces, each chamber communicating with a common ink duct passing through the said plate and extending symmetrically between and parallel to the rows of nozzles, characterised in that the duct comprises a first chamber of substantially parallelepipedal form communicating with the said expulsion chambers and a second chamber of substantially truncated pyramidal form communicating with the said first chamber through a truncation base of the said second chamber, the said truncation base being parallel to the said surfaces of the said plate and being located in a position intermediate between the said surfaces.

17. Head as claimed in claim 16, characterised

in that the said first chamber is defined by two parallel side walls and by a base parallel and opposite to the said truncation base, the said opposite base lying in a first of the said surfaces.

18. Head as claimed in one of claims 16 and 17, characterised in that the said second chamber is defined by a larger base parallel and opposite to the said truncation base and lying in a second of the said surfaces of the said plate. 5

19. Head as claimed in claim 17, wherein the said support plate is of crystalline silicon cut in accordance with a crystallographic orientation of  $\langle 100 \rangle$ , characterised in that the said second chamber is moreover defined by two plane side walls inclined with respect to the said larger base by a characteristic angle, the said side walls being obtained by an etching treatment. 10 15

20. Head as claimed in any one of claims 16 to 19, characterised in that the said first chamber is produced by means of a sandblasting operation. 20

21. Head as claimed in any one of claims 16 to 19, characterised in that the said first chamber is produced by means of an excimer laser beam. 25

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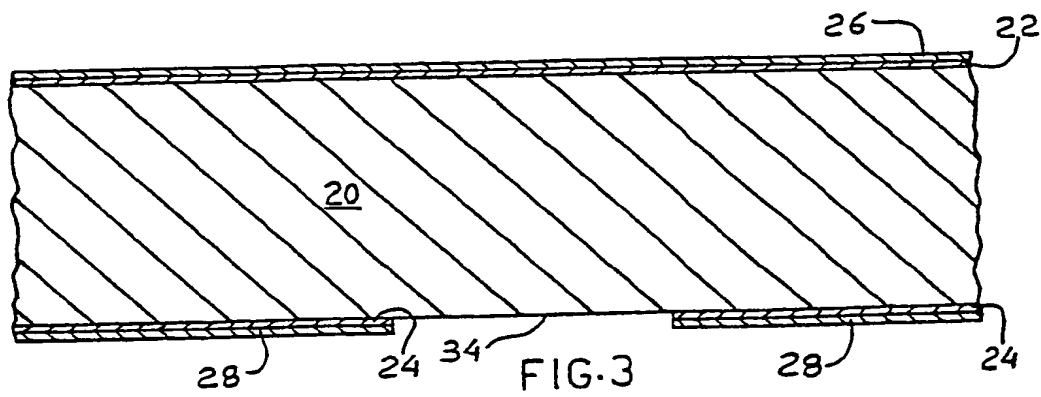
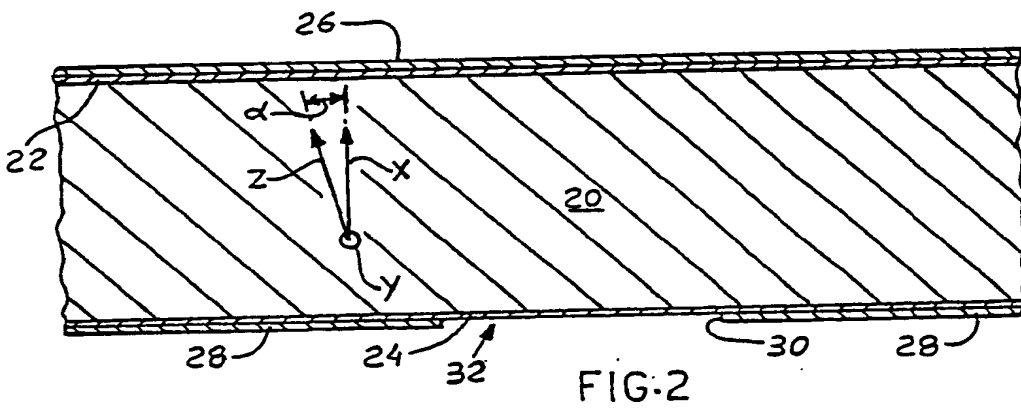
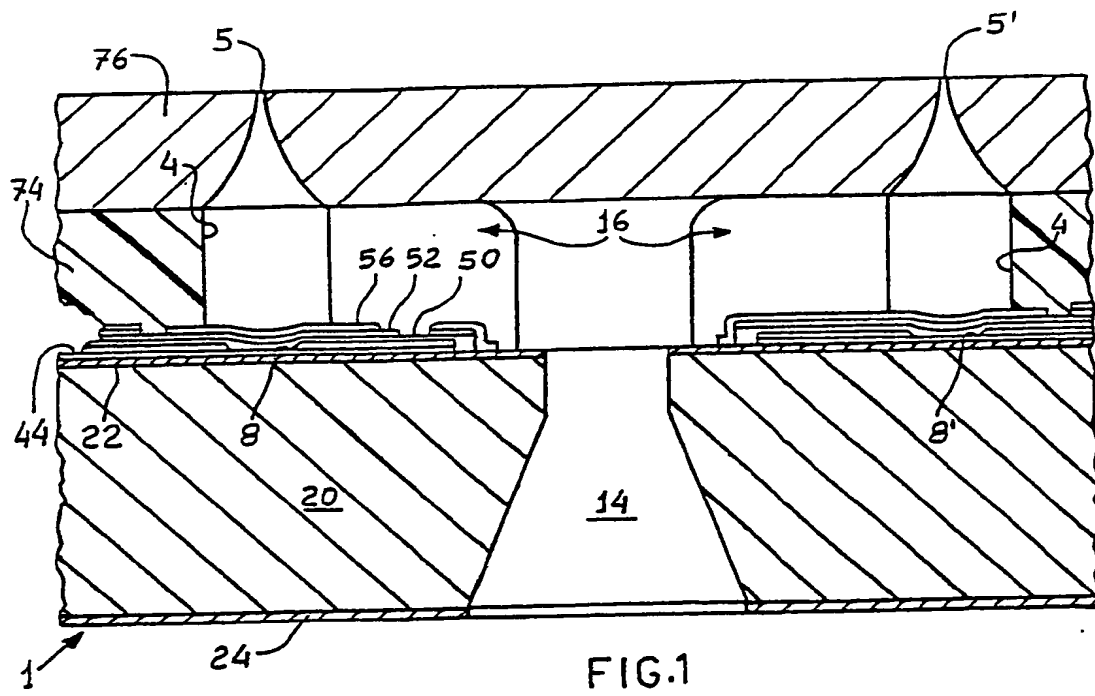
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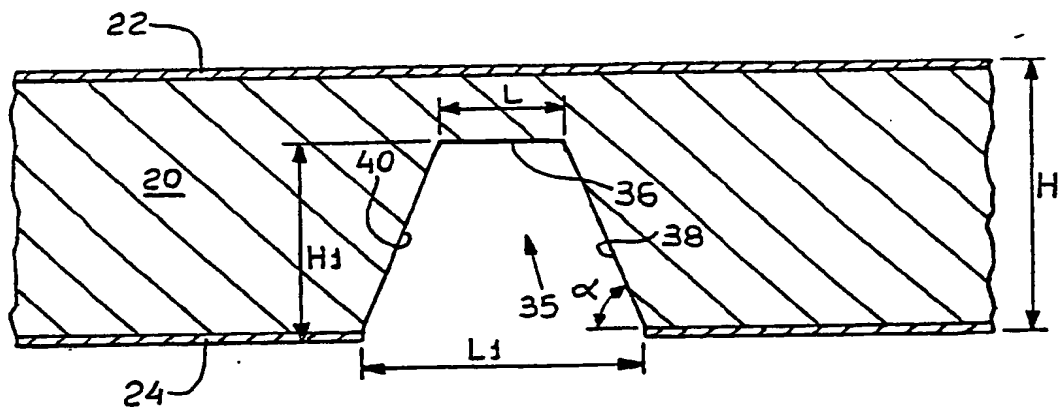


FIG. 4

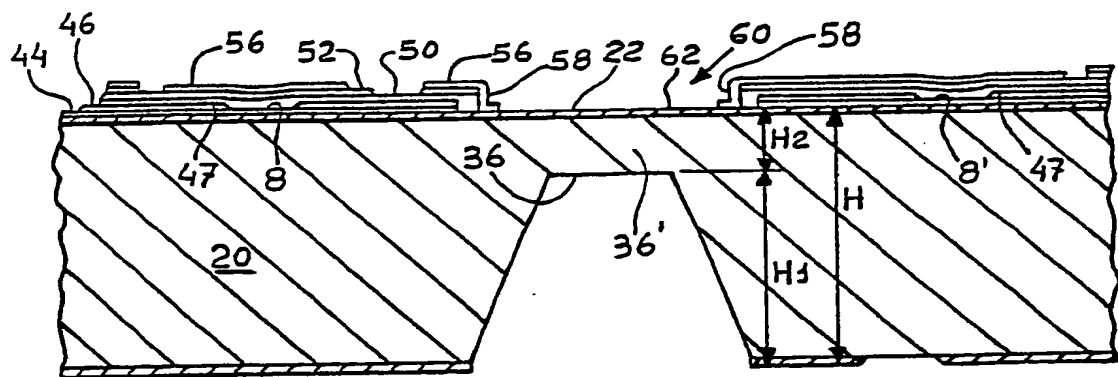


FIG. 5

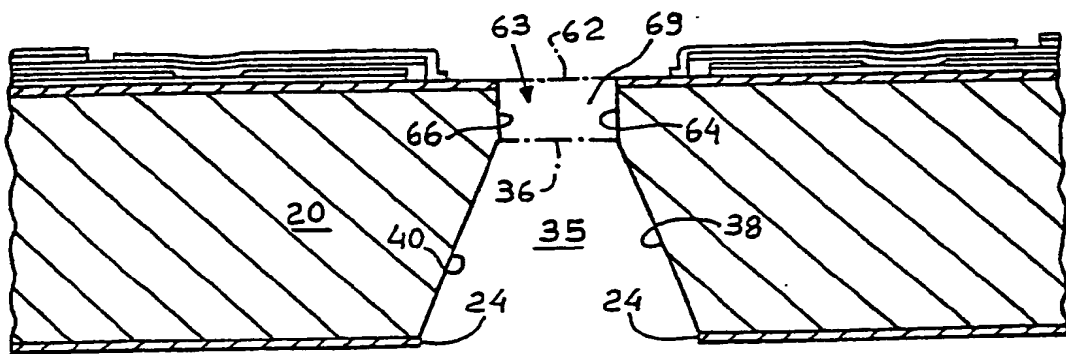


FIG. 6



FIG.7

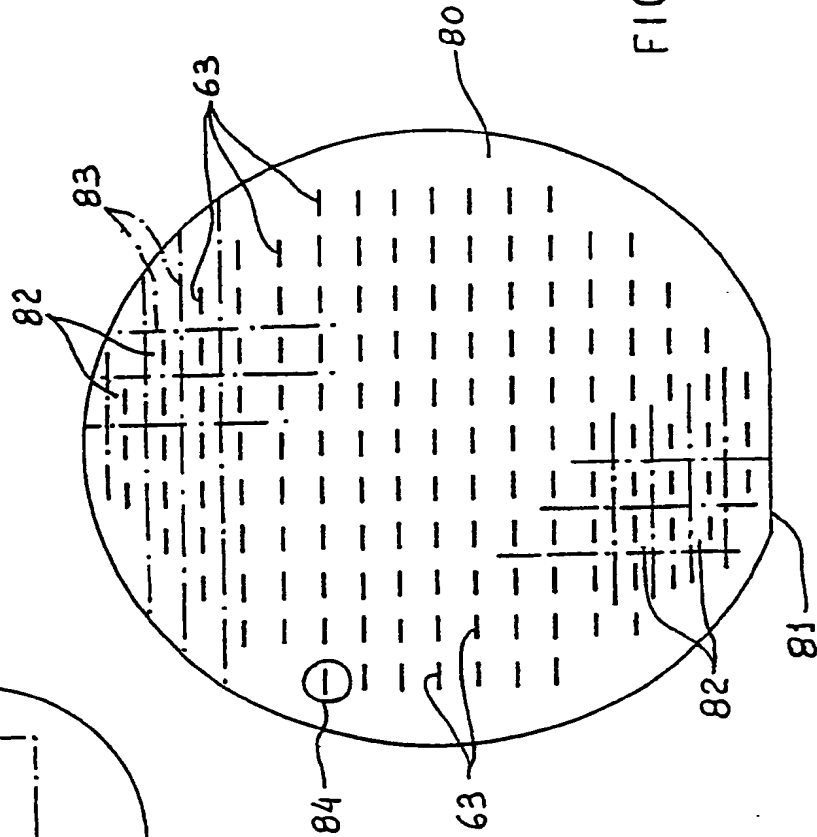
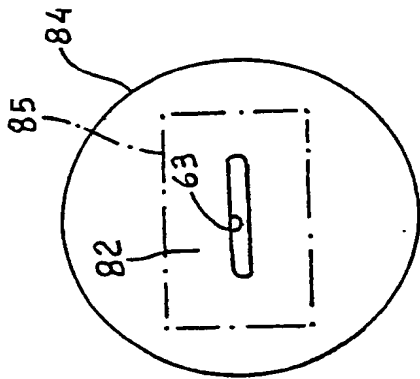


FIG.8





(19)



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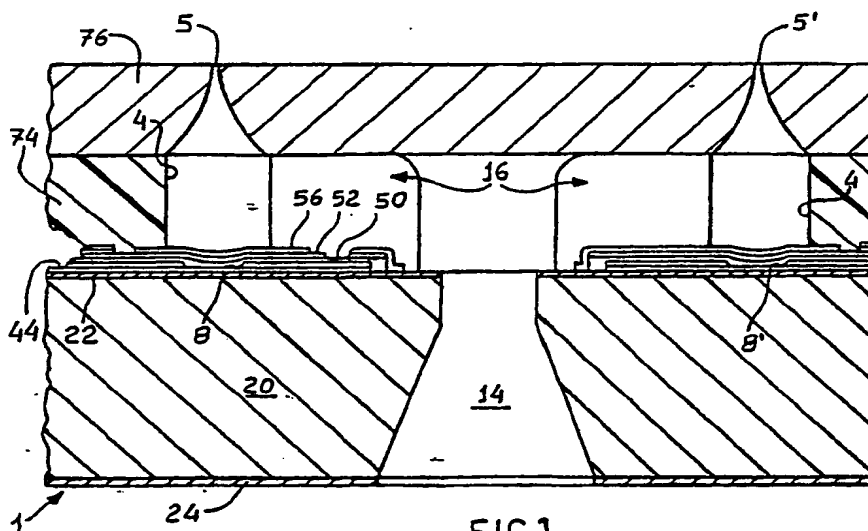
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**FIG.1****EP 0 401 996 A3**



European Patent  
Office

## EUROPEAN SEARCH REPORT

Application Number

DOCUMENTS CONSIDERED TO BE RELEVANT			EP 90305432.8
Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int. Cl.5)
A	<u>US - A - 4 789 425</u> (DRAKE) * Totality * --	1-3, 9-16	B 41 J 2/16 B 41 J 2/05
A	<u>US - A - 4 835 553</u> (TORPEY) * Totality * --	1-3, 9-16	
A	<u>EP - A2 - 0 197 723</u> (XEROX CORP.) * Totality * --	1-3, 9-16	
A	<u>EP - A2 - 0 224 937</u> (HEWLETT-PACKARD) * Totality * ----	16	
			TECHNICAL FIELDS SEARCHED (Int. Cl.5)
			B 41 J G 01 D
The present search report has been drawn up for all claims			
Place of search VIENNA		Date of completion of the search 01-10-1991	Examiner WITTMANN
<b>CATEGORY OF CITED DOCUMENTS</b> X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons * : member of the same patent family, corresponding document			

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